#### **TELEFUNKEN Semiconductors**

## 2.9 GHz PLL for SAT TV Receiver with Universal Bus

#### **Features**

- 2.9 GHz divide-by-16 prescaler integrated
- 3 selectable reference divider ratios:
  ÷ 256 / ÷ 512 / ÷ 1024
- Universal bus:

I<sup>2</sup>C-bus **or** 3-wire-bus I<sup>2</sup>C-bus software compatible to U6204B 3-wire-bus software compatible to U6358B (19 bit)

- I<sup>2</sup>C-bus mode:
  - 5 switching outputs (open collector) 4 addresses selectable at pin 10 for multituner application

- 3-wire-bus mode:
  - 4 switching outputs (open collector) Locksignal output (open collector)
- Low power consumption (typical 5 V / 23 mA)
- Electrostatic protection according to MIL-STD 883

Package: SO16 small

## **Block Diagram**

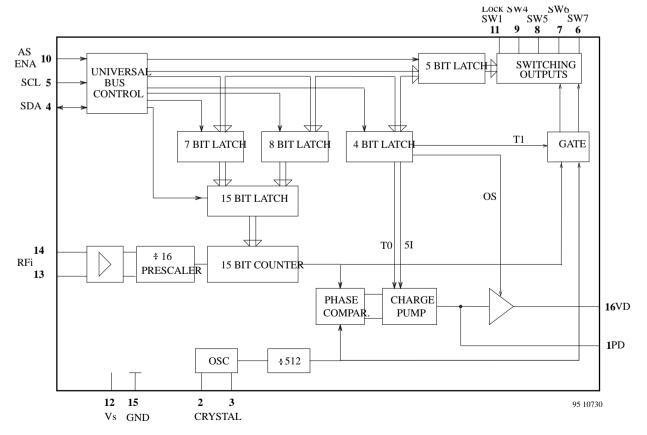
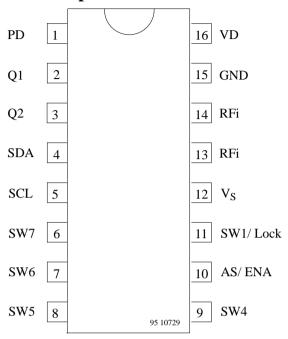


Figure 1. Block diagram

# **Pin Description**



Pin	Symbol	Function
1	PD	Charge pump output
2	Q1	Crystal
3	Q2	Crystal
4	SDA	Data in/output
5	SCL	Clock input
6	SW7	Switching output open collector
7	SW6	Switching output open collector
8	SW5	Switching output open collector
9	SW4	Switching output open collector
10	AS / ENA	Address select / enable input
11	SW1 / Lock	Switching / lock output open
		collector
12	Vs	Supply voltage
13	RFi	RF input
14	RFi	RF input
15	GND	Ground
16	VD	Active filter output

Figure 2.

## **Absolute Maximum Ratings**

All voltages are referred to GND (Pin 15)

Parameters	Symbol	Value	Unit
Supply voltage Pin 12	Vs	-0.3 to 6	V
RF input voltage Pin 13, 14	RFi	-0.3 to Vs+0.3	V
Switching output current open collectors Pin 6 – 9, 11	SW 1, 4-7	−1 to 15	mA
Total current of switching outputs Open collectors Pin 6 – 9, 11	SW 1, 4-7	50	mA
Switching output voltage Pin 6 – 9, 11 in off state: in on state:	SW 1, 4-7	-0.3 to 14 -0.3 to 6	V V
Bus input/output voltage Pin 4 Pin 5	VSDA VSCL	-0.3 to 6 -0.3 to 6	V V
SDA output current open collector Pin 4	ISDA	-1 to 5	mA
Address select voltage Pin 10	VAS / ENA	-0.3 to Vs+0.3	V
Charge pump output voltage Pin 1	PD	-0.3 to Vs+0.3	V
Active filter output voltage Pin 16	VD	-0.3 to Vs+0.3	V
Crystal oscillator voltage Pin 2	Q1	-0.3 to Vs+0.3	V
Reference divider switch voltage, Pin 3	RDS	$-0.3$ to $V_S + 0.3$	V
Junction temperature	T <sub>jmax</sub>	-40 to 125	°C
Storage temperature	$T_{stg}$	-40 to 125	°C



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## **Operating Range**

All voltages are referred to GND (Pin 15)

Parameters	Symbol	Min.	Тур.	Max.	Unit
Supply voltage Pin 12	Vs	4.5	5.5		V
Ambient temperature	T <sub>amb</sub>	0	70		°C
Input frequency Pin 13, 14	$R_{Fi}$	250	2900		MHz
Progr. divider	$S_{\mathrm{F}}$	256	32767		

## **Thermal Resistance**

Parameters	Symbol	Value	Unit
Junction ambient	$R_{thJA}$	110	K/W

## **Electrical Characteristics**

Test conditions:  $V_S = 5$  V,  $T_{amb} = 25$ °C, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply current	SW 1, 4, 5, 6, 7 = 0					
	Pin 12	Is	18	23	28	mA
Input sensitivity						
Input frequency	fi = 250 MHz, Pin 13	Vi 1)	100		300	mVrms
	fi = 750-2900 MHz, Pin 13	Vi 1)	20		300	mVrms
Crystal oscillator						
Recommended crystal						
series resistance			10		200	Ω
Crystal oscillator drive						
level	Pin 2			50		mVrms
Crystal oscillator source	Nominal spread ±15%					
impedance	Pin 2			-650		Ω
External reference input	AC coupled sinewave					
frequency	Pin 2		2		8	MHz
External reference input	AC coupled sinewave					
amplitude	Pin 2		70		200	mVrms
Switching outputs (SW4–7	, Pin 6–9), lock output, open co	llector(SW1/	lock, Pin 11	)		
Leakage current	VH = 13.5 V	IL			10	μΑ
Saturation voltage	IL = 10  mA	VSL <sup>2)</sup>			0.5	V
Charge pump output (PD)						
Charge pump current 'H'	5I = H, VPD = 2 V					
	Pin 1	IPDH		±180		μΑ
Charge pump current 'L'	5I = L, VPD = 2 V					
	Pin 1	IPDL		±50		μΑ
Charge pump leakage	T0 = 0, VPD = 2 V					
current	Pin 1	IPDTRI		±5		nA
Charge pump amplifier						
gain	Pin 1, 16			6400		
<b>Bus inputs</b> (SDA, SCL)						
Input voltage	Pin 4, 5	Vi 'H'	3		5.5	V
-	Pin 4, 5	Vi 'L'			1.5	V

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# U6223B-AFP

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Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit	
Input current	VSCL 'H' = $Vs$ Pin 4, 5	li 'H'			10	μΑ	
	VSCL 'L' = $0 \text{ V}$ Pin 4, 5	li 'L'	-10			μΑ	
Leakage current	Vs = 0 V Pin 4, 5	IL			10	μΑ	
Output voltage SDA (open	ISDA 'L' = $2 \text{ mA}$ , Pin 4	VSDA 'L'			0.4	V	
collector)							
Address selection / Enable	Address selection / Enable input (SA, ENA)						
Input current	VAS 'H' = Vs Pin 10	liAS 'H'			10	μΑ	
	VAS 'L' = $0$ Pin $10$	liAS 'L'	-100			μA	

- 1) RMS-voltage calculated from the measured available power on 50  $\Omega$
- 2) Tested with one switch active, the collector voltage may not exceed 6 V

#### **Description**

The U6223B is a single chip PLL designed for SAT receiver systems. It consists of a divide-by-16 prescaler (up to 2.9 GHz) with an integrated preamplifier, a 15 bit programmable divider, a crystal oscillator with a reference divider with three selectable divider ratios  $(\div 256 / \div 512 / \div 1024)$ , a phase/frequency detector together with a charge-pump, which is driving the tuning amplifier. Only one external transistor is required for varactor line driving. The device can be controlled via I<sup>2</sup>C-bus format or the 3-wire-bus format. It detects automatically which bus format is received, therefore there is no need for a bus selection pin. In I<sup>2</sup>C-bus mode the device has four programmable addresses, programmed by applying a specific input voltage to the address select input, enabling the use of up to four synthesizers in a system. The same pin serves in 3-wirebus mode as the enable signal input. Five open collector outputs for switching functions are included, which are capable of sinking at least 10 mA. One of these open collector outputs serves as Locksignal output in the 3-wire-bus mode.

#### **Functional Description**

The U6223B is programmed via 2-wire I<sup>2</sup>C bus or 3-wire bus depending on the received data format. The three bus inputs pins 4, 5 and 10 are used as SDA, SCL and address select inputs in I<sup>2</sup>C-bus mode and as data, clock and enable inputs in 3-wire bus mode. The data includes the scaling factor SF (15 bit) and switching output information. In I<sup>2</sup>C-bus mode there are some additional functions for testing of the device included.

#### **Oscillator Frequency Calculation**

fvco = 16 \* SPF \* frefosc / 512

fvco: Locked frequency of voltage controlled

oscillator

SPF: Scaling factor of programmable

15-bit-divider

SRF: Scaling factor of reference divider:

÷256/ ÷512/ ÷1024

frefosc: Reference oscillator frequency:

3.2 / 4 MHz crystal or external

reference frequency

The input amplifier together with a divide-by-16 prescaler gives an excellent sensitivity (see 'Typical Prescaler Input Sensitivity'). The input impedance is shown in the diagram 'Typical Input Impedance'. When a new divider ratio according to the requested fyco is entered, the phase detector and charge pump together with the tuning amplifier adjusts the control voltage of the VCO until the output signals of the programmable divider and the reference divider are in frequency and phase locked. The reference frequency may be provided by an external source capacitively coupled into Pin 2, or by using an on-board crystal with an 18 pF capacitor in series. The crystal operates in the series resonance mode. The reference divider division ratio is selectable to  $\div$  256 /  $\div$  512 /  $\div$  1024. Therefore with a 4 MHz crystal and nominal division ratio of 512 of the reference divider the comparison frequency is 7.8125 kHz, which gives 125 kHz steps for the VCO, or with a 3.2 MHz crystal respectively 6.25 kHz comparison frequency and 100 kHz VCO step size. In addition there are switching outputs available for bandswitching and other purposes.

## Application

The U6223B is function and pin evivalent to the U6225B apart from the switchable reference divider. A typical application is shown on page ?. All input / output interface circuits are shown on page ?. Some special features which are related to test- and alignment procedures for tuner production are explained together within the following bus mode description.

## **U6223B-AFP**

#### I<sup>2</sup>C-Bus Description

When the U6223B is controlled via 2-wire I<sup>2</sup>C-bus format, then data and clock signals are fed into the SDA and SCL lines respectively. The table 'I<sup>2</sup>C-BUS DATA FORMAT' describes the format of the data and shows how to select the device address by applying a voltage at pin 10. When the correct address byte is received, the SDA line is pulled low by the device during the acknowledge period, and then also during the acknowledge periods, when additional data bytes are programmed. After the address transmission (first byte), data bytes can be sent to the device. There are four data bytes requested to fully program the device. The table 'I<sup>2</sup>C-BUS PULSE DIAGRAM' shows some possible data transfer examples.

Programmable divider bytes PDB1 and PDB2 are stored in a 15 bit latch and are controlling the division ratio of the 15 bit programmable divider. The control Byte CB1 allows to control the following special functions:

- 5I-bit switches between low and high charge pump current
- T1-bit enables divider test mode when it is set to logic 1
- T0-bit allows to disable the charge pump when it is set to logic 1
- RD1 and RD2-bit allow to select the reference divider factor
- OS-bit disable the charge pump drive amplifier output when it is set to logic 1.

Only in  $I^2C$  bus mode the charge pump current can be controlled. In 3-wire-bus mode there is always the high charge pump current active. The OS-bit function disables the complete PLL function. This allows the tuner alignment by suppling the tuning voltage directly through the 30~V supply voltage of the tuner.

The control byte CB2 programs the switching outputs SW 1, 4, 5, 6, 7; a logic 0 for high impedance output (off) and a logic 1 for low impedance output (on).

Description		I <sup>2</sup> C-Bus Data Format							
	MSB	MSB LSB							
Address byte	1	1	0	0	0	AS1	AS2	0	A
Progr. divider byte 1	0	n14	n13	n12	n11	n10	n9	n8	A
Progr. divider byte 2	n7	n6	n5	n4	n3	n2	n1	n0	A
Control byte 1	1	5I	T1	T0	X	RD2	RD1	OS	A
Control byte 2	SW7	SW6	SW5	SW4	X	X	SW1	X	A

A = Acknowledge; X = not used; Unused bits of controlbyte 2 should be 0 for lowest power consumption

**n0 ... n14** Scaling factor (SF) SF = 16384\*n14+8192\*n13+...+2\*n1+n0

**T0, T1** Testmode selection T1 = 1: divider test mode on

T1 = 0: divider test mode off T0 = 1: charge pump disable

T0 = 0: charge pump enable

SW1, 4, 5, 6, 7 Switching outputs SW1, SW4, SW5, SW6, SW7 = 1: open collector active

Charge pump current switch 5I = 1: high current 5I = 0: low current

OS Output switch OS = 1: varicap driver disable

OS = 0: varicap drive enable

**RD1, RD2** Reference divider selection

RD2	RD1	Reference Divider Ratio
0	0	1024
0	1	off
1	0	256
1	1	512

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# I<sup>2</sup>C-Bus Pulse Diagram

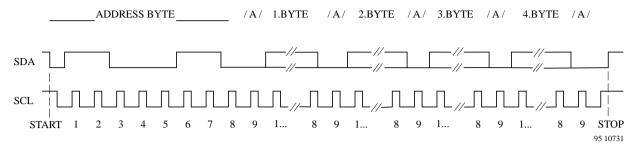


Figure 3.

Data transfer examples

START ADR PDB1 PDB2 CB1 CB2 STOP START ADR CB1 CB2 PDB1 PDB2 STOP START ADR PDB1 PDB2 CB1 STOP START ADR CB1 CB2 PDB1 STOP START ADR PDB1 PDB2 STOP

START ADR CB1 CB2 STOP

START ADR CB1 STOP

Description

START = Start condition

ADR = Address byte

PDB1 = Progr. divider byte 1

PDB2 = Prgr. divider byte 2

CB1 = Control byte 1

CB2 = Control byte 2

STOP = Stop condition

# I<sup>2</sup>C-Bus Timing

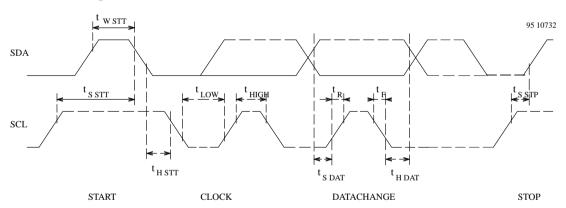


Figure 4.

Parameters	Symbol	Min.	Тур.	Max.
Rise time SDA, SCL	tR		15	μs
Fall time SDA, SCL	tF		15	μs
Clock frequency SCL	fSCL	0	100	kHz
Clock 'H' pulse	tHIGH	4		μs
Clock 'L' pulse	tLOW	4		μs
Hold time start	tH STT	4		μs
Waiting time start	tW STT	4		μs
Set-up time start	tS STT	4		μs
Set-up time stop	tS STP	4		μs
Set-up time data	tS DAT	0.3		μs
Hold time data	tH DAT	0		μs

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#### **3-Wire-Bus Description**

When the U 6225 B-B is controlled via 3-wire bus format, then DATA, CLOCK and ENABLE signals are fed into the SDA, SCL and AS/ENA lines respectively. The diagram '3-WIRE-BUS PULSE DIAGRAM' shows the data format. The data consist of a single word, which contains the programmable divider and switch information. Only during the enable high period the data is clocked into the internal data shift register on the negative clock transition. During enable low periods the clock input is disabled. New data words are only accepted by the internal data latches from the shift register on a negative transition of the enable signal when during the high period of the enable exactly nineteen clock pulses were send. The data sequence and the timing is described in the following diagrams.

In 3-wire-bus mode pin 11 becomes automatically the Locksignal output. An improved lock detect circuit generates a flag when the loop has attained lock. 'In lock' is indicated by a low impedance state (on) of the open collector output.

In 3-wire-bus mode there is always the high charge pump current active. Only in I<sup>2</sup>C-bus mode the charge pump current can be controlled.

The complete PLL function can be disabled by programming a normally not used division ratio of zero. This allows the tuner alignment by supplying the tuning voltage directly through the 30 V supply voltage of the tuner.

### 3-Wire-Bus Pulse Diagram

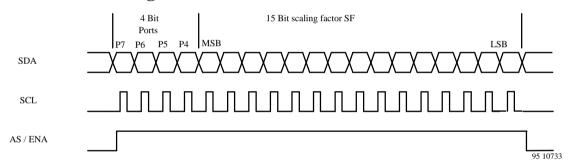


Figure 5.

## 3-Wire-Bus Timing

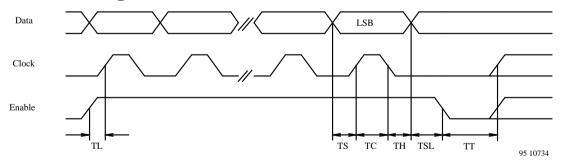


Figure 6.

Parameters	Symbol	Min.	Тур.	Unit
Set up time	TS	2		μs
Enable hold time	TSL	2		μs
Clock width	TC	2		μs
Enable set up time	TL	10		μs
Enable between two transmissions	TT	10		μs
Data hold time	TH	2		μs

## **Input/Output Interface Circuits**

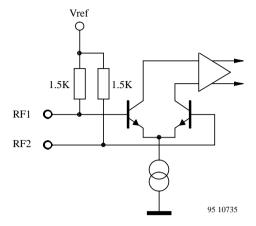


Figure 7. RF input

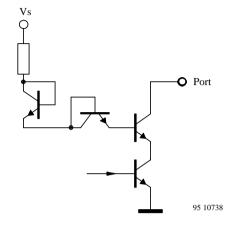


Figure 10. Ports

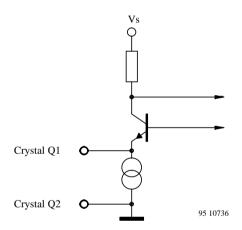


Figure 8. Reference oscillator

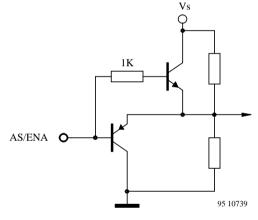


Figure 11. Address select/ Enable input

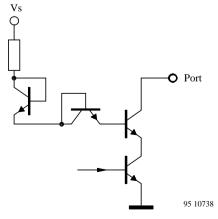


Figure 9. SCL SDA input

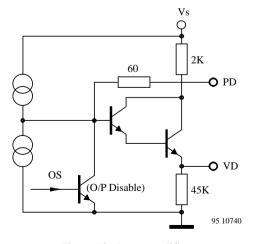


Figure 12. Loop amplifier

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## **Typical Prescaler Input Sensitivity**

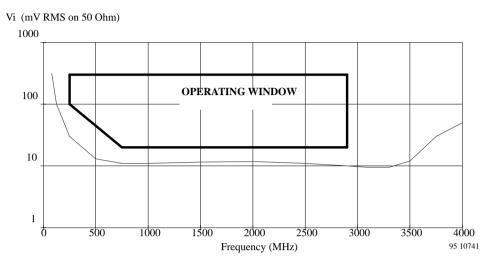


Figure 13.

# **Typical Input Impedance**

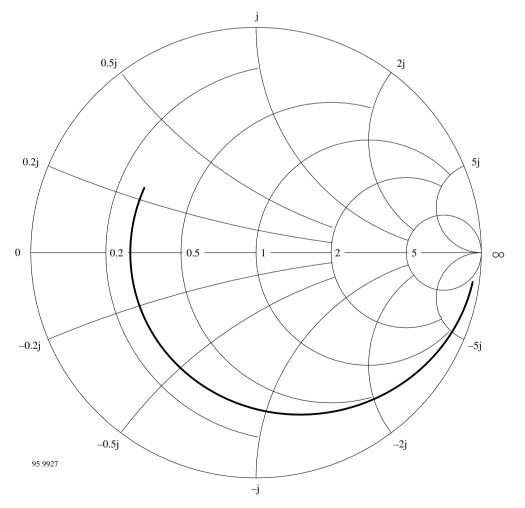


Figure 14.

# **U6223B-AFP**

## **Application Circuit**

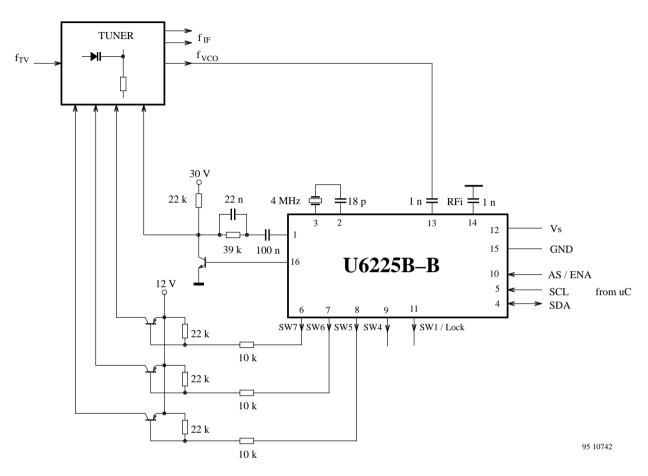
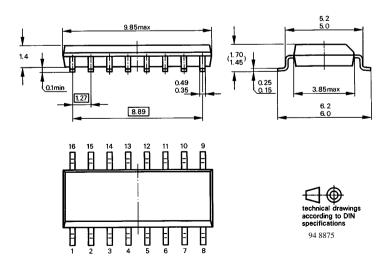


Figure 15.

## **Dimensions in mm**

Package: SO-16 small





## **Ozone Depleting Substances Policy Statement**

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423